technology!

(b) Compare microwave amplifier with microwave oscillators.

[Turn Over

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- (a) Discuses generator tuning networks for microwave oscillators. 6.
 - (b) A GaAs FET is biased for minimum nose figure and has following S- parameters and noise parameters at 4 GHz ($Z_0 = 100\Omega$). Design an amplifier with 2dB noise figure maximum gain compatible with this noise figure. Assume device R is unilateral.

$$S = \begin{bmatrix} 0.6 < -60^{0} & 0.05 < 26^{0} \\ 1.9 < 81^{0} & 0.5 < -60^{0} \end{bmatrix}$$

$$F_{min} = 1.6 dB$$
, $(\bar{\Gamma}_{opt}) = 0.62 < 100^{\circ}$, $R_{N} = 20\Omega$

- Write short note on (any two):-7.
 - (a) Noise figure test equipments
 - (b) Power distributed amplifiers
 - (c) Microwave resonators

b

a

a